

Production and Characterization of Ce³⁺: Si₂N₂O Phosphors for White Light-Emitting Diodes

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Abstract : Si₂N₂O (Sinoite) is an inorganic-based oxynitride material that reveals promising phosphor candidates for white light-emitting diodes (WLEDs). However, there is now limited knowledge to explain the synthesis of Si₂N₂O for this purpose. Here, to the best of authors' knowledge, we report the first time the production of Si₂N₂O based phosphors by CeO₂, SiO₂, Si₃N₄ from main starting powders, and Li₂O sintering additive through spark plasma sintering (SPS) route. The processing parameters, e.g., pressure, temperature, and sintering time, were optimized to reach the monophasic Si₂N₂O containing samples. The lattice parameter, crystallite size, and amount of formation phases were characterized in detail by X-ray diffraction (XRD). Grain morphology, particle size, and distribution were analyzed by scanning and transmission electron microscopes (SEM and TEM). Cathodoluminescence (CL) in SEM and photoluminescence (PL) analyses were conducted on the samples to determine the excitation, and emission characteristics of Ce³⁺ activated Si₂N₂O. Results showed that the Si₂N₂O phase in a maximum 90% ratio was obtained by sintering for 15 minutes at 1650°C under 30 MPa pressure. Based on the SEM-CL and PL measurements, Ce³⁺: Si₂N₂O phosphor shows a broad emission summit between 400-700 nm that corresponds to white light. The present research was supported by TUBITAK under project number 217M667.

Keywords : cerium, oxynitride, phosphors, sinoite, Si₂N₂O

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